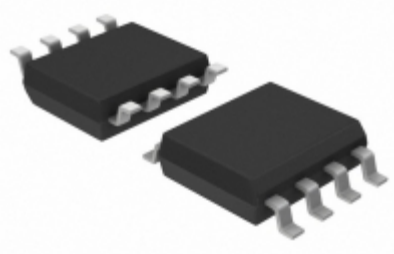




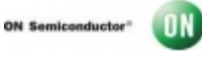
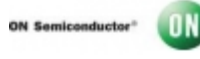




	<h2 style="color: red;">NTMS4920NR2G</h2>	
	Hersteller-Teilenummer:	NTMS4920NR2G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 30V 10.6A 8SOIC
	Datenblätter:	 NTMS4920NR2G.pdf
	RoHs Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, 30049 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	NTMS4920NR2G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 10.6A 8SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	30049 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Verlustleistung (max)	820mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10.6A (Ta)
Rds On (Max) @ Id, Vgs	4.3 mOhm @ 7.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	58.9nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4068pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)




















NTMS4920NR2G ist neu im Original, Suche NTMS4920NR2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMS4920NR2G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMS4920NR2G: Info@Y-IC.com

Sie können auch interessiert sein:

 NTMS4917UT001 ON NTMS4917UT001 ON	 NTMS4935NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 10A 8SOIC	 NTMS4937N AMI Semiconductor / ON Semiconductor NTMS4937N ON	 NTMS4920N AMI Semiconductor / ON Semiconductor NTMS4920N ON
 NTMS4916UT001 ON NTMS4916UT001 ON	 NTMS4917NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 10.2A SO8FL	 NTMS4939NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8A 8SOIC	 NTMS4937NR2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.6A 8SOIC

heiße Teile

Mehr

 NTMS4503NR2G	 NTMS4700NR	 NTMS4700NR2G	 NTMS4704NR2G	 NTMS4705NR2G
 NTMS4706NR2G	 NTMS4800NR2G	 NTMS4801N	 NTMS4801NR2G	 NTMS4802N
 NTMS4802NR2G	 NTMS4807N	 NTMS4807NR2G	 NTMS4816N	 NTMS4816NG
 NTMS4816NR2G	 NTMS4840NR2G	 NTMS4872NR2G	 NTMS4873NFR2G	 NTMS4916AS001
 NTMS4916N	 NTMS4916NR2G	 NTMS4916UT001	 NTMS4917NR2G	 NTMS4917UT001
 NTMS4920N	 NTMS4937N	 NTMS4937NR2G	 NTMS4939N	 NTMS4939NR2G
 NTMS4N01R2	 NTMS4P01R2G	 NTMS5835NL	 NTMS5835NLR2G	 NTMS5838NLR2G
 NTMS5P02	 NTMS5P02R2	 NTMS5P02R2G	 NTMS7N03R2	 NTMS7N03R2G
 NTMS7N03R2R2G	 NTMSD2P102LR2	 NTMSD2P102R2	 NTMSD3P102R2	 NTMSD3P102R2SG
 NTMSD3P303R2	 NTMSD6N03R2G	 NTMSD6N303R2	 NTMSD6N303R2G	 NTMSD6N303R2SG

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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